

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.

Substitute for form 1449B/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

Date Submitted: March 7, 2005

(use as many sheets as necessary)

Complete if Known 10/526745

Application Number	Unassigned
Filing Date	03/07/2005
First Named Inventor	Katsuya HASEGAWA
Group Art Unit	Unassigned
Examiner Name	Unassigned
Attorney Docket Number	017700-0174

Sheet 1 of 1

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
	A1	2004/0224851	A	KAKIMOTO et al.	11-11-2004	
	A2	6,743,533	B1	KAKIMOTO et al.	06-01-2004	
	A3	5,687,899		YOSHIDA et al.	03-04-1997	

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Documents	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
	A4	JP	2000-299026		FUJIKURA LTD.	10-24-2000		A
	A5	JP	07-291626		SUMITOMO ELECTRIC IND. LTD.	11-07-1995		A

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
	A6	"Material Engineering for Studying with Personal Computer," The 2001 Seminar of Japan Institute of Metals, November 2001, pp. 21-31.	
	A7	K. HASEGAWA et al., "Preparation of SmBa ₂ Cu ₃ O _y Films With Improved In-plane Alignment," J. Japan Inst. Metal., Vol. 66, 2002, pp. 320-328.	
	A8	M. NAKAMURA et al., "Fabrication of Single Crystal of SmBa ₂ Cu ₃ O _{7-x} by the Modified Top-Seeded Solution Growth Method in Low Oxygen Partial Pressure Atmosphere, Japan J. of Applied Phys., Vol. 34, 1995, pp. 6031-6035.	
	A9	T. MURATA et al., "Interface Structures in NdBCO/MgO and YBCO/MgO Superconducting Films Grown by LPE Method," The Fourth Pacific Rim International Conference of Advanced Materials and Processing, 2001, pp. 729-732, The Japan Institute of Metals.	
	A10	K. SUDOH et al., "Superconducting properties and surface morphology of SmBa ₂ Cu ₃ O _{6+δ} thin films," Physica C, Vol. 357-360, 2001, pp. 1358-1360; Elsevier Science.	
	A11	Y. WU et al., "Atomic configurations of YBa ₂ Cu ₃ O _{7-x} /MgO interfaces," Physica C 371, 2002, pp. 309-314, Elsevier Science.	
		DUPLICATE OF 08/03/2005	

Examiner
Signature

/Kallambella Vijayakumar/

Date
Considered

03/25/2008

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document.

⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

Burden Hour Statement: This form is estimated to take 2.0 hours to complete. Time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.